



LED Display

Product Data Sheet

LTS-5001AJD

Spec No.: DS30-2001-223

Effective Date: 10/29/2001

Revision: -

LITE-ON DCC

RELEASE

BNS-OD-FC001/A4

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FEATURES

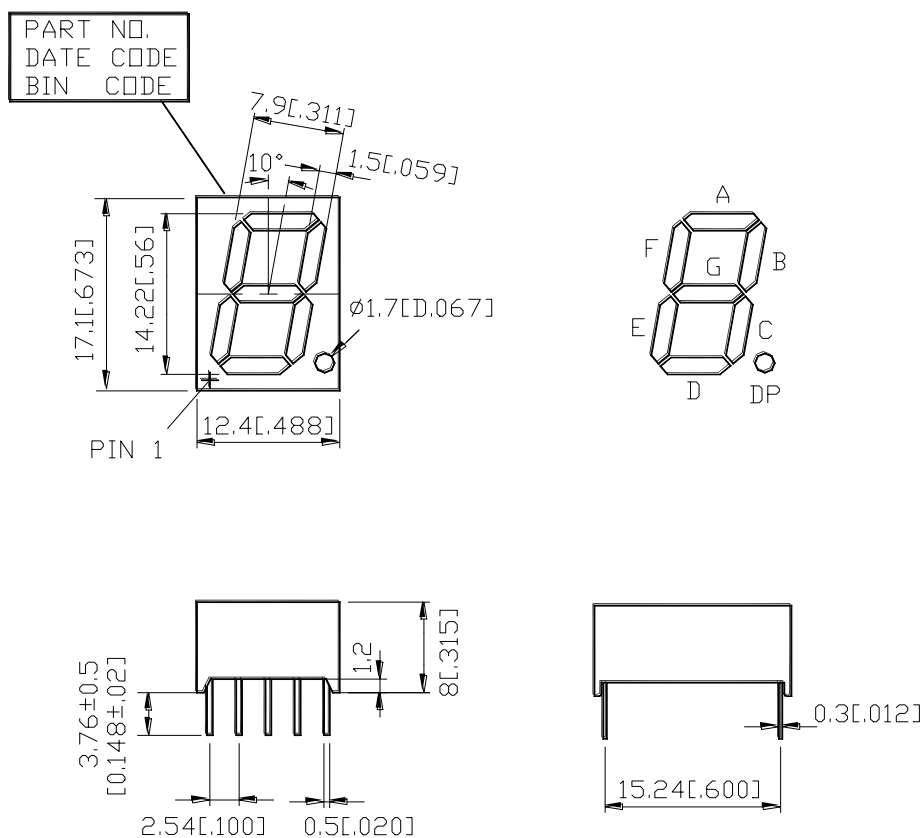
- * 0.56 inch (14.22 mm) DIGIT HEIGHT.
- * CONTINUOUS UNIFORM SEGMENTS
- * LOW POWER REQUIREMENT.
- * EXCELLENT CHARACTERS APPEARANCE.
- * HIGH BRIGHTNESS & HIGH CONTRAST.
- * WIDE VIEWING ANGLE.
- * SOLID STATE RELIABILITY.
- * CATEGORIZED FOR LUMINOUS INTENSITY.

DESCRIPTION

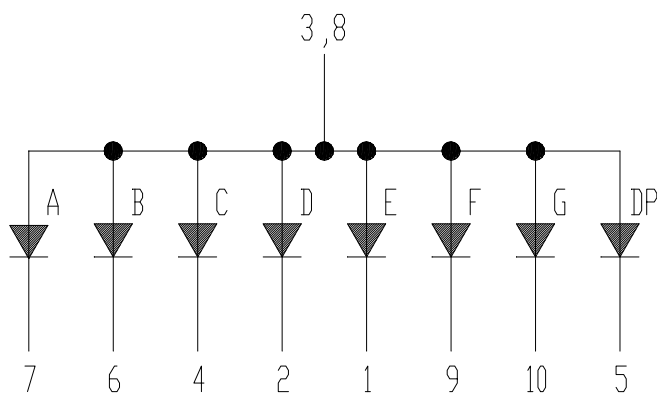
The LTS-5001AJD is a 0.56 inch (14.22 mm) digit height single digit seven-segment display. This device utilizes AlInGaP hyper red LED chips, which are made from AlInGaP on a non-transparent GaAs substrate, and has a gray face and white segments.

DEVICE

| PART NO. | DESCRIPTION |
|-------------------|----------------------------------|
| AlInGaP HYPER RED | COMMON ANODE RT. HAND DECIMAL |
| LTS-5001AJD | |

PACKAGE DIMENSIONS


NOTES: All dimensions are in millimeters. Tolerances are ± 0.25 mm (0.01") unless otherwise noted.

INTERNAL CIRCUIT DIAGRAM


PIN CONNECTION

| NO | CONNECTION |
|-----------|-------------------|
| 1 | CATHODE E |
| 2 | CATHODE D |
| 3 | COMMON ANODE |
| 4 | CATHODE C |
| 5 | CATHODE D.P. |
| 6 | CATHODE B |
| 7 | CATHODE A |
| 8 | COMMON ANODE |
| 9 | CATHODE F |
| 10 | CATHODE G |

ABSOLUTE MAXIMUM RATING AT Ta=25°C

| PARAMETER | MAXIMUM RATING | UNIT |
|--|----------------|-------|
| Power Dissipation Per Segment | 70 | mW |
| Peak Forward Current Per Segment (1/10 Duty Cycle, 0.1ms Pulse Width) | 90 | mA |
| Continuous Forward Current Per Segment | 25 | mA |
| Derating Linear From 25°C Per Segment | 0.33 | mA/°C |
| Reverse Voltage Per Segment | 5 | V |
| Operating Temperature Range | -35°C to +85°C | |
| Storage Temperature Range | -35°C to +85°C | |
| Solder Temperature: max 260°C for max 3sec at 1.6mm below seating plane. | | |

ELECTRICAL / OPTICAL CHARACTERISTICS AT Ta=25°C

| PARAMETER | SYMBOL | MIN. | TYP. | MAX. | UNIT | TEST CONDITION |
|-----------------------------------|-------------------|------|------|------|------|----------------------|
| Average Luminous Intensity | I _v | 320 | 700 | | μcd | I _F =1mA |
| Peak Emission Wavelength | λ _p | | 650 | | nm | I _F =20mA |
| Spectral Line Half-Width | Δλ | | 20 | | nm | I _F =20mA |
| Dominant Wavelength | λ _d | | 639 | | nm | I _F =20mA |
| Forward Voltage Per Segment | V _F | | 2.1 | 2.6 | V | I _F =20mA |
| Reverse Current Per Segment | I _R | | | 100 | μA | V _R =5V |
| Luminous Intensity Matching Ratio | I _v -m | | | 2:1 | | I _F =1mA |

Note: Luminous intensity is measured with a light sensor and filter combination that approximates the CIE (Commision International De L'Eclairage) eye-response curve.

TYPICAL ELECTRICAL / OPTICAL CHARACTERISTIC CURVES

(25°C Ambient Temperature Unless Otherwise Noted)

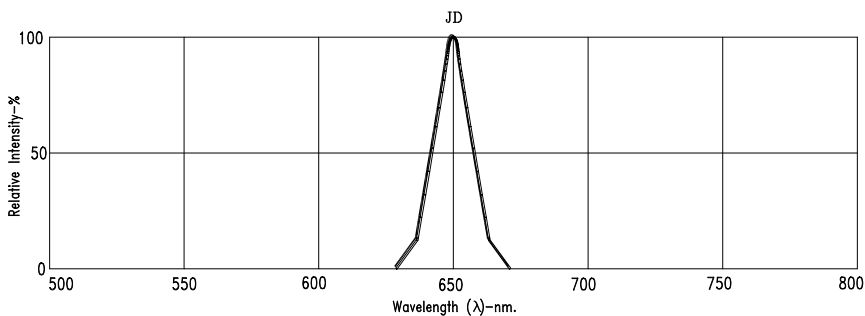


Fig1. RELATIVE INTENSITY VS. WAVELENGTH

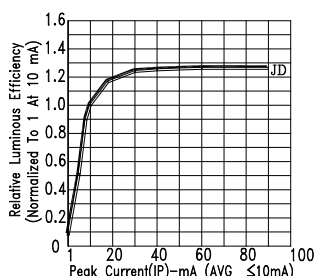


Fig2. RELATIVE LUMINOUS EFFICIENCY (LUMINOUS INTENSITY PER UNIT CURRENT) VS. PEAK CURRENT

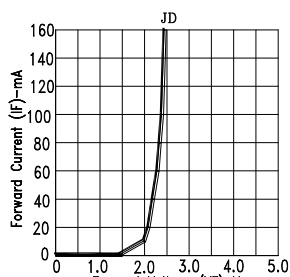


Fig3. FORWARD CURRENT VS. FORWARD VOLTAGE

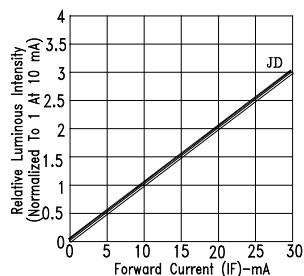


Fig4. RELATIVE LUMINOUS INTENSITY VS. FORWARD CURRENT

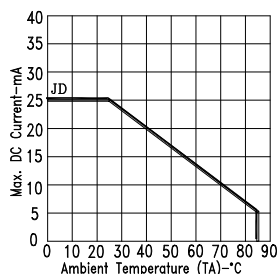


Fig5. MAX. ALLOWABLE DC CURRENT VS. AMBIENT TEMPERATURE.

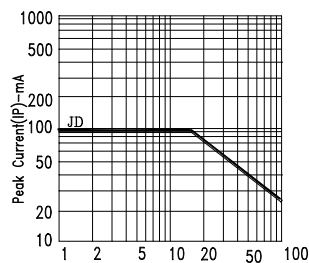


Fig6. MAX. PEAK CURRENT VS. DUTY CYCLE % (REFRESH RATE 1KHz)

NOTE : JD=AlInGaP HYPER RED

Mouser Electronics

Authorized Distributor

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